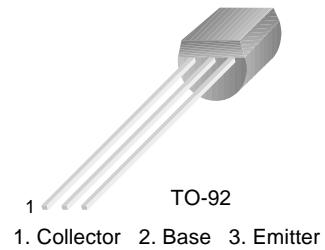


BC327/328

Switching and Amplifier Applications

- Suitable for AF-Driver stages and low power output stages
- Complement to BC337/BC338



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CES}	Collector-Emitter Voltage : BC327 : BC328	-50 -30	V
V_{CEO}	Collector-Emitter Voltage : BC327 : BC328	-45 -25	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current (DC)	-800	mA
P_C	Collector Power Dissipation	625	mW
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CEO}	Collector-Emitter Breakdown Voltage : BC327 : BC328	$I_C = -10\text{mA}$, $I_B = 0$	-45 -25			V
BV_{CES}	Collector-Emitter Breakdown Voltage : BC327 : BC328	$I_C = -0.1\text{mA}$, $V_{BE} = 0$	-50 -30			V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E = -10\mu\text{A}$, $I_C = 0$	-5			V
I_{CES}	Collector Cut-off Current : BC327 : BC328	$V_{CE} = -45\text{V}$, $V_{BE} = 0$ $V_{CE} = -25\text{V}$, $V_{BE} = 0$		-2 -2	-100 -100	nA
h_{FE1} h_{FE2}	DC Current Gain	$V_{CE} = -1\text{V}$, $I_C = -100\text{mA}$ $V_{CE} = -1\text{V}$, $I_C = -300\text{mA}$	100 40		630	
$V_{CE}(\text{sat})$	Collector-Emitter Saturation Voltage	$I_C = -500\text{mA}$, $I_B = -50\text{mA}$			-0.7	V
$V_{BE}(\text{on})$	Base-Emitter On Voltage	$V_{CE} = -1\text{V}$, $I_C = -300\text{mA}$			-1.2	V
f_T	Current Gain Bandwidth Product	$V_{CE} = -5\text{V}$, $I_C = -10\text{mA}$, $f = 20\text{MHz}$		100		MHz
C_{ob}	Output Capacitance	$V_{CB} = -10\text{V}$, $I_E = 0$, $f = 1\text{MHz}$		12		pF

h_{FE} Classification

Classification	16	25	40
h_{FE1}	100 ~ 250	160 ~ 400	250 ~ 630
h_{FE2}	60-	100-	170-

Typical Characteristics

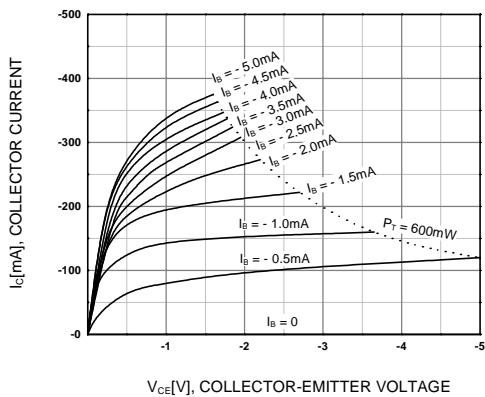


Figure 1. Static Characteristic

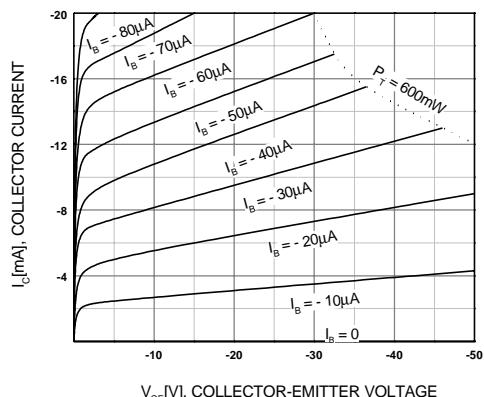


Figure 2. Static Characteristic

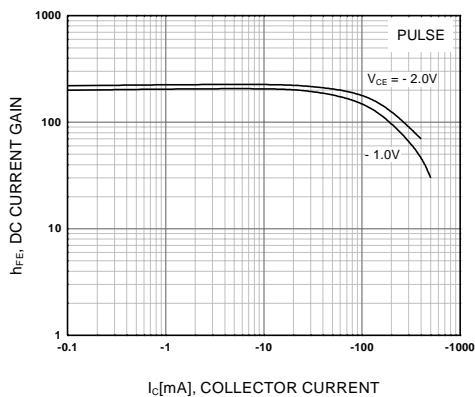


Figure 3. DC current Gain

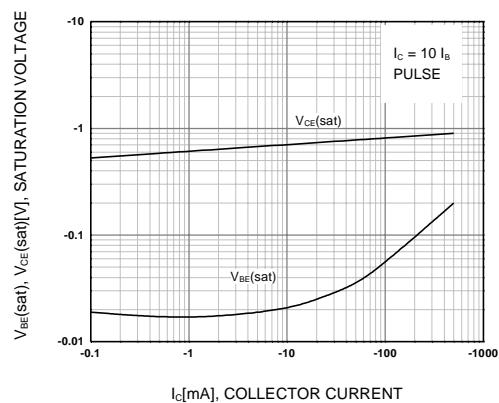


Figure 4. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

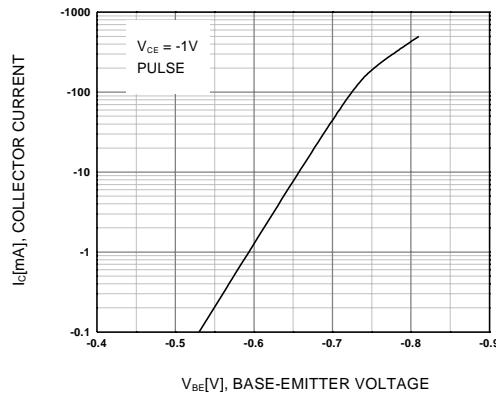


Figure 5. Base-Emitter On Voltage

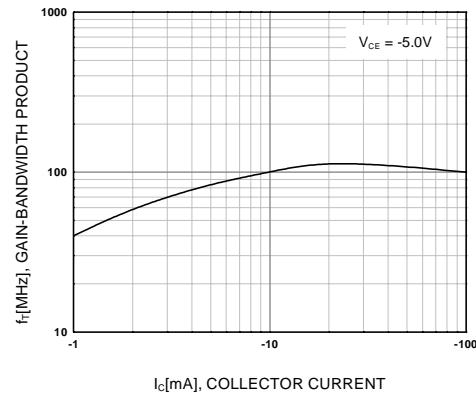
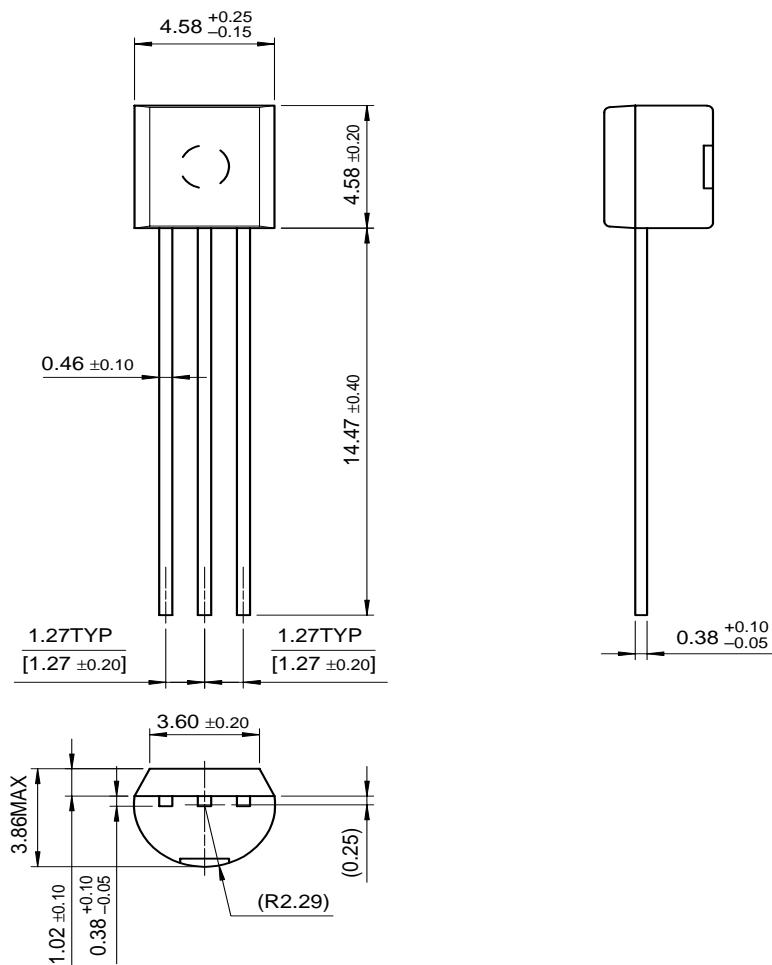


Figure 6. Gain Bandwidth Product

Package Dimensions

TO-92



Dimensions in Millimeters

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